

	<p>SI4401BDY-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI4401BDY-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 40V 8.7A 8-SOIC</p> <p>Datenblätter:  SI4401BDY-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6822 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4401BDY-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 40V 8.7A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	6822 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	1.5W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.7A (Ta)
Rds On (Max) @ Id, Vgs	14 mOhm @ 10.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	55nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)






























SI4401BDY-T1-GE3 ist neu im Original, Suche SI4401BDY-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4401BDY-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4401BDY-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4401BDY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 40V 8.7A 8-SOIC</p>	 <p>SI4401BDY-T1-E3 Vishay / Siliconix MOSFET P-CH 40V 8.7A 8-SOIC</p>	 <p>SI4401DDY-T1-E3 VISHAY SI4401DDY-T1-E3 VISHAY</p>	 <p>SI4401BDY-T1-E3. VISHAY SI4401BDY-T1-E3. VISHAY</p>
 <p>SI4401DDY-T1-GE3 Vishay / Siliconix MOSFET P-CH 40V 16.1A 8-SOIC</p>	 <p>SI4401BDY-T1 VISHAY VISHAY SOP8</p>	 <p>SI4401BDY VISHAY SI4401BDY VISHAY</p>	 <p>SI4401BDY-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 40V 8.7A 8-SOIC</p>

heiße Teile

Mehr

 SI4388DY	 SI4388DY-T1-GE3	 SI4388DY-T1-GE3	 SI4390DY	 SI4390DY-T1
 SI4390DY-T1-E3	 SI4390DY-T1-E3	 SI4390DY-T1-E3	 SI4392ADY	 SI4392ADY-T1-E3
 SI4392DY	 SI4392DY-T1-E3	 SI4392DY-T1-E3.	 SI4392DY-T1-E3..	 SI4394DY
 SI4394DY-T1-E3	 SI4396DY	 SI4396DY-T1-E3	 SI4396DY-T1-E3	 SI4398DY-T1-E3
 SI4398DY-T1-E3	 SI4401BDY-T1-E3	 SI4401BDY-T1-E3	 SI4401BDY-T1-E3.	 SI4401BDY-T1-GE3
 SI4401DDY	 SI4401DDY-T1-E3	 SI4401DDY-T1-GE3	 SI4401DDY-T1-GE3	 SI4401DY-T1-E3
 SI4401DY-T1-E3	 SI4403BDY-T1-E3	 SI4403BDY-T1-E3	 SI4403BDY-T1-E3.	 SI4403CDY-T1-GE3
 SI4403CDY-T1-GE3	 SI4403DY-T1-E3	 SI4404DY	 SI4404DY-D1	 SI4404DY-T1
 SI4404DY-T1-E3	 SI4404DY-T1-E3	 SI4404DY-T1-E3.	 SI4404DY-T1-GE3	 SI4404DY-T1-GE3
 SI4405BDY-T1-GE3	 SI4405DY-T1-E3	 SI4405DY-T1-GE3	 SI4406DY	 SI4406DY-T1

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